## NSN 5961-01-122-7618

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-122-7618 **Inclosure Material:** Metal **Overall Length:** 0.468 inches **Terminal Length:** 0.900 inches **Overall Height:** 0.200 inches **Overall Width:** 0.312 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 50.0 working peak reverse voltage, peak total value, gate terminal open-circuited all semiconductor device diode **Current Rating Per Characteristic:** 100.00 milliamperes collector current, dc absolute all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 62.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: